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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No. : 09/870,530 Confirmation No. 1349
Applicant : Chia-Hsing Chen
Filed : May 1, 2001
TC/A.U. : 2825
Examiner : Renzo Rocchegiani

Docket No. : 046602-00367
Customer No. : 29381

Mail Stop RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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AMENDMENT

Sir:

This paper is in response to the Advisory Action dated April 16, 2003.

Applicant files with this paper a Request for Continued Application under 37 CFR 1.114 of prior application Serial No. 09/870,530, filed on May 31, 2001, entitled METHOD FOR FORMING NITRIDE READ ONLY MEMORY WITH INDIUM POCKET REGION. Prior to examining this RCE, kindly amend the application in accordance with the following particulars:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.